

# SANYO Semiconductors

DATA SHEET



# N-Channel Silicon MOSFET **General-Purpose Switching Device Applications**

# Features

- · Low ON-resistance.
- Low Qg.
- · Ultrahigh-speed switching.

# Specifications

#### Absolute Maximum Ratings at Ta=25°C

Symbol	Conditions	Ratings	Unit
VDSS		600	V
VGSS	3	±30	V
ID	A 15-10	3.5	А
IDP	PW≤10μs, duty cycle≤1%	12	А
D-	3.12 6	2.0	W
PD	Tc=25°C	25	W
Tch		150	°C
Tstg		-55 to +150	°C
EAS		49	mJ
AV		3	А
	VDSS VGSS ID IDP PD Tch Tstg EAS	VDSS V   VGSS ID   ID ID   IDP PW≤10µs, duty cycle≤1%   PD Tc=25°C   Tch Tc=25°C   Tstg EAS	VDSS 600   VGSS ±30   ID 3.5   IDP PW≤10µs, duty cycle≤1%   PD Tc=25°C   Tch 150   Tstg -55 to +150   EAS 49

1 VDD=50V, L=10mH, IAV=3A

\*2 L≤10mH, single pulse

### Electrical Characteristics at Ta=25°C

Parameter		Symbol	Conditions	Ratings			Unit
				min	typ	max	Unit
Drain-to-Source Breakdown Voltage		V(BR)DSS	ID=1mA, VGS=0V	600			V
Zero-Gate Voltage Drain Current		IDSS	V <sub>DS</sub> =600V, V <sub>GS</sub> =0V			1.0	mA
Gate-to-Source Leakage Current		IGSS	V <sub>GS</sub> =±30V, V <sub>DS</sub> =0V			±100	nA
Cutoff Voltage		VGS(off)	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA	3.5		5.5	V
Marking : K2624 Continued on next page							

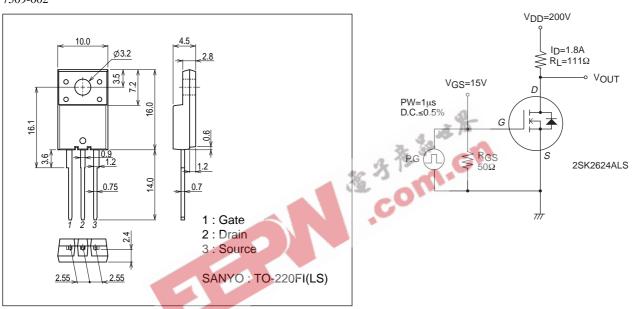
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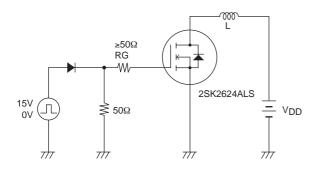
Parameter	Symbol	Conditions	Ratings			Unit
	Symbol	Conditions	min	typ	max	Unit
Forward Transfer Admittance	yfs	VDS=10V, ID=1.8A	1.0	2.0		S
Static Drain-to-Source On-State Resistance	R <sub>DS</sub> (on)	ID=1.8A, VGS=15V		2.0	2.6	Ω
Input Capacitance	Ciss	VDS=20V, f=1MHz		550		pF
Output Capacitance	Coss	VDS=20V, f=1MHz		165		pF
Reverse Transfer Capacitance	Crss	V <sub>DS</sub> =20V, f=1MHz		85		pF
Total Gate Charge	Qg	VDS=200V, ID=3A, VGS=10V		15		nC
Turn-ON Delay Time	t <sub>d</sub> (on)	See specified Test Circuit.		17		ns
Rise Time	tr	See specified Test Circuit.		17		ns
Turn-OFF Delay Time	td(off)	See specified Test Circuit.		40		ns
Fall Time	tf	See specified Test Circuit.		22		ns
Diode Forward Voltage	V <sub>SD</sub>	IS=3A, VGS=0V		0.98	1.2	V

#### Package Dimensions

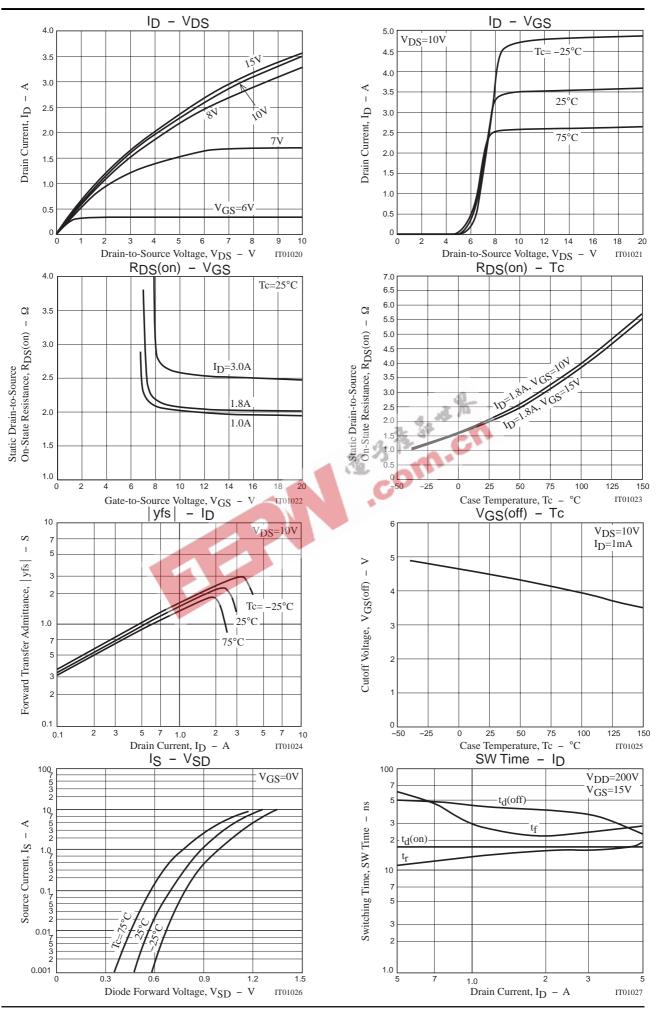
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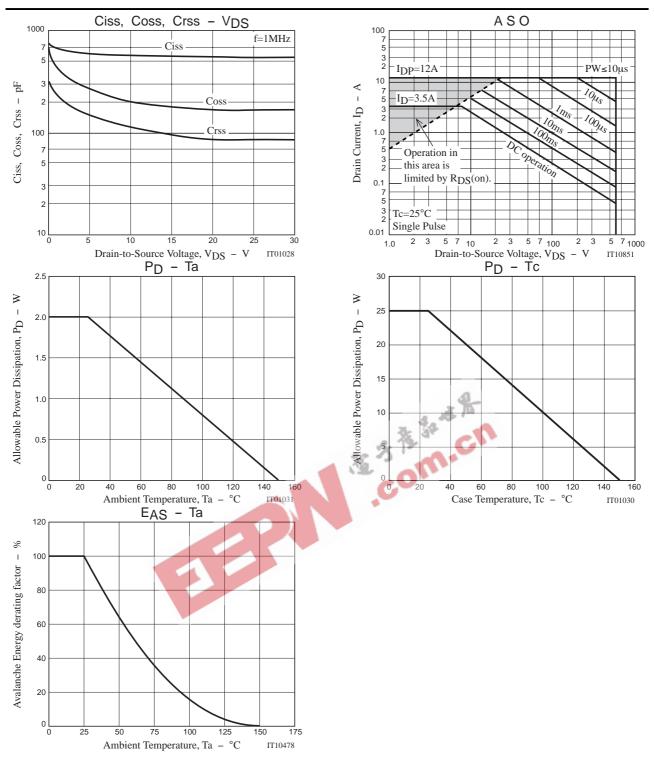


#### Avalanche Resistance Test Circuit



# Switching Time Test Circuit





Note on usage : Since the 2SK2624ALS is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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